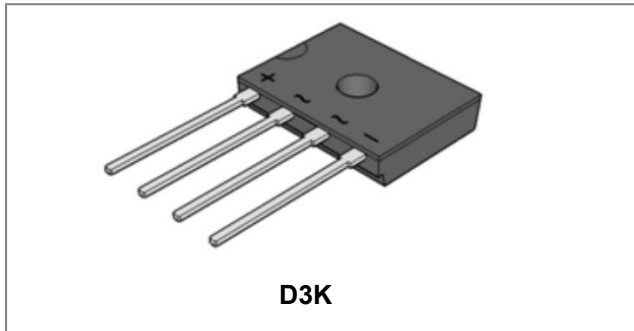


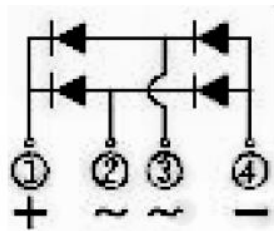
UG3KB05 THRU UG3KB100
Single-Phase 3.0A Glass Passivated Bridge Rectifier



Features

- Glass passivated die construction
- Low forward voltage drop
- High current capability
- High surge current capability
- Designed for surface mount application
- Plastic material-UL flammability 94V-0
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: D3K, Molded plastic
- Terminals: Plated leads solderable per MIL-STD-202, Method 208
- Polarity: as marked on case
- Mounting Position: Any
- Lead Free: For RoHS / Lead Free Version

Maximum Ratings: @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Type Number	Symbol	UG3K B05	UG3K B10	UG3K B20	UG3K B40	UG3K B60	UG3K B80	UG3K B100	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_{DC}	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Average Rectified Output Current Without heat sink @T _A = 30°C With heat sink @T _A = 140°C	I_o	1.5 3.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	60							A

Electrical Characteristics:

Type Number	Symbol	UG3K B05	UG3K B10	UG3K B20	UG3K B40	UG3K B60	UG3K B80	UG3K B100	Units
Forward Voltage (per element) * @ $I_F = 3.0A$	V_F					1.1			V
Peak Reverse Current * @ $T_A = 25^\circ C$ At Rated DC Blocking Voltage * @ $T_A = 125^\circ C$	I_R					5.0 500			μA
Typical Junction Capacitance(per leg) (Note 1)	C_J					21			pF

* Pulse width < 300 μs , duty cycle < 2%

Thermal-Mechanical Specifications:

Type Number	Symbol	UG3K B05	UG3K B10	UG3K B20	UG3K B40	UG3K B60	UG3K B80	UG3K B100	Units
Typical Thermal Resistance (per leg)	$R_{\theta JA}$ $R_{\theta JL}$					55 15			$^\circ C/W$
Operating and Storage Temperature Range	T_J, T_{STG}					-55 to +150			$^\circ C$

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

Ratings and Characteristics Curves

Fig. 1 Output Current Derating Curve

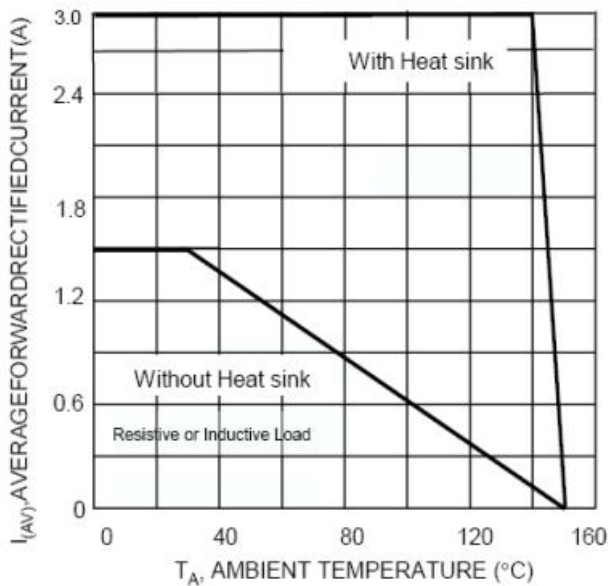


Fig. 2 Typical I Forward Characteristics (per leg)

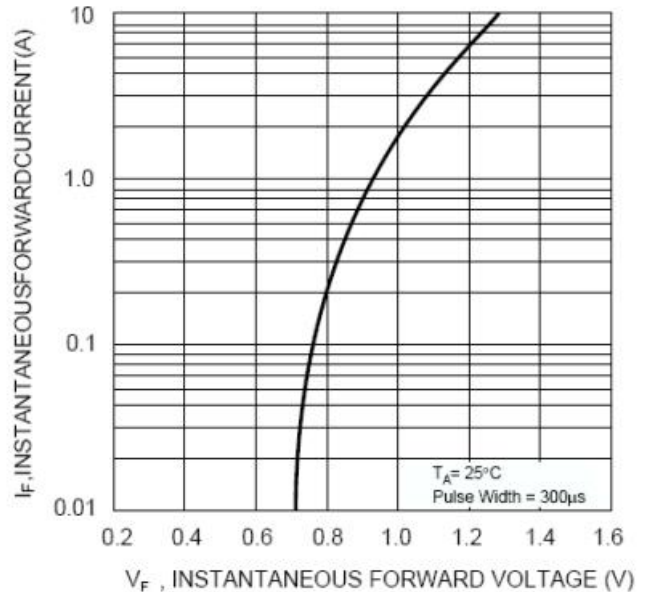


Fig. 3 Maximum Peak Forward Surge Current (per leg)

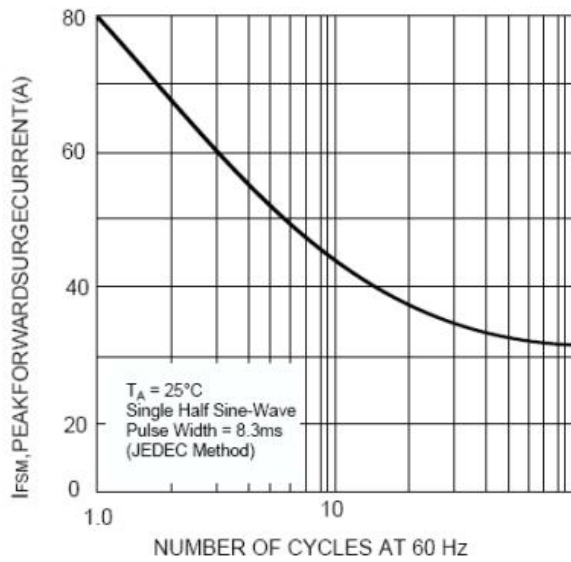


Fig.4 Typical Junction Capacitance Per Diode

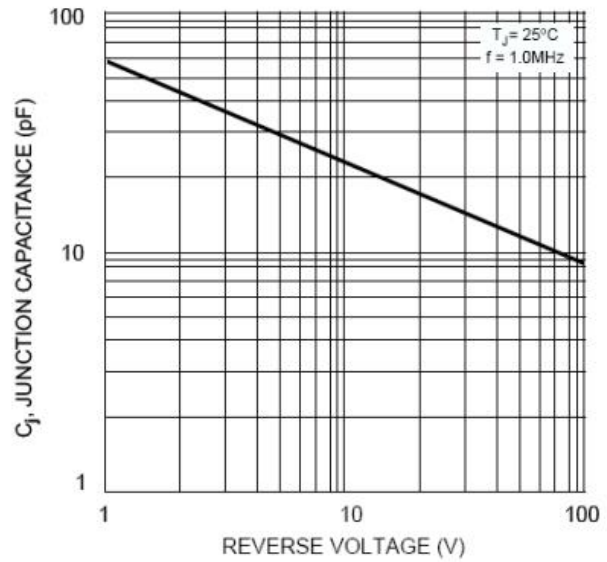
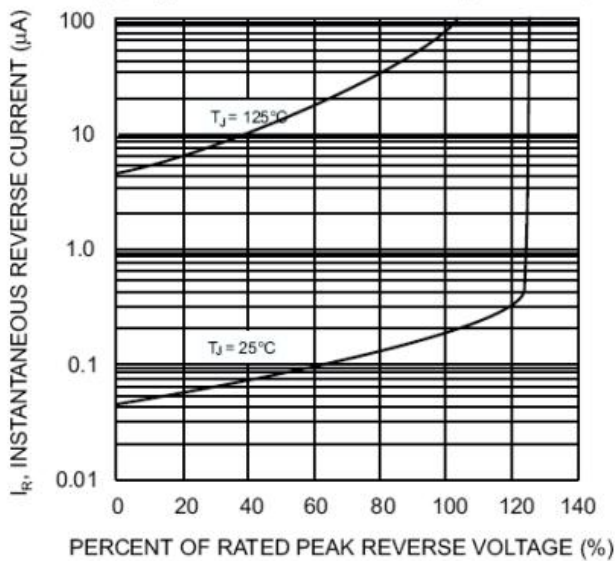


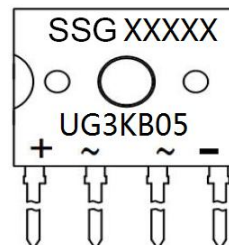
Fig. 5 Typical Reverse Characteristics (per element)



Ordering Information

Device	Package	Plating	Shipping
UG3KB05 THRU UG3KB100	D3K(Pb-Free)	Pure Sn	37pcs / tube

Marking Diagram

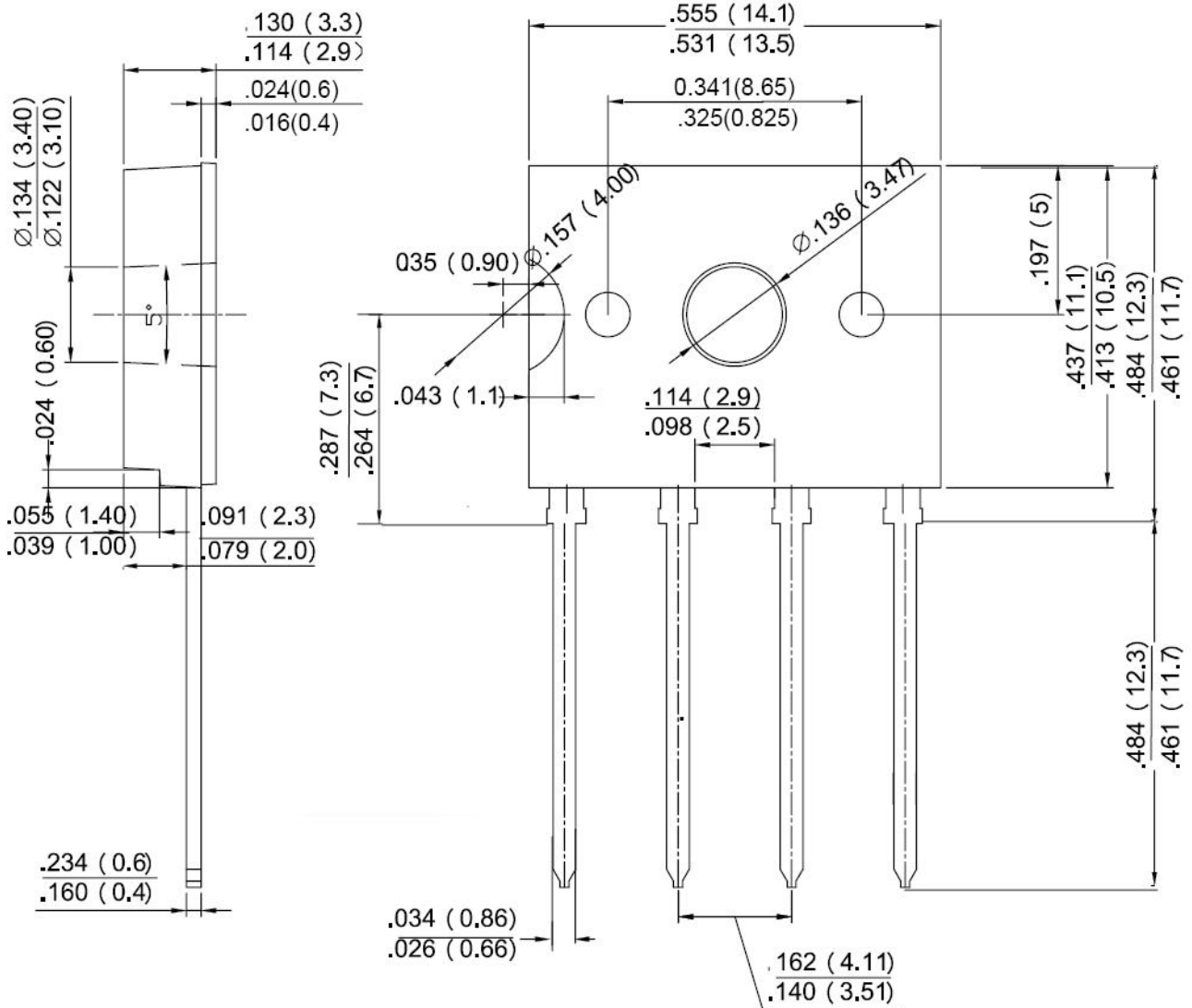


Where XXXXX is YYWWL

SSG = SSG
YY = Year
WW = Week
L = Lot Number
UG3KB05 = Type Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Mechanical Dimensions D3K (Inches/Millimeters)



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- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
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